MAS110S

Fast Turn-off Asymmetric Thyristor/Diode Module

Replaces April 1999 version, DS4200-4.0 DS4200-5.0 January 2000

APPLICATIONS

- High Frequency High Power Choppers And Inverters.
- Ultrasonic Generators.
- Welding.
- PWM Inverters.

KEY PARAMETERS

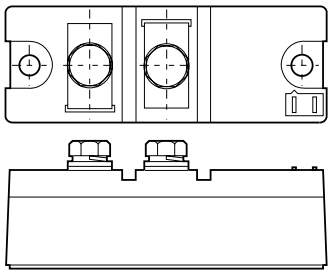
V_{DRM}	1400V
I_{TSM}	2000A
$I_{T(AV)}$ per arm	110A
V_{isol}	2500V
t_q	10/12/15μs

DESCRIPTION

The MAS 110S is a fast thyristor/diode module in an electrically isolated package. The semiconductors are are pressure contact mounted giving high resistance to thermal fatigue, and having excellent heat dissipation qualities.

Isolation medium is non-toxic alumina.

The MAS110S is recognised under the 'Recognised Component Program of Underwriters Laboratories Inc. USA. File number E151069.



Outline type code: MAS110S
See Package Details for further information.

Fig.1 Package outline (not to scale)

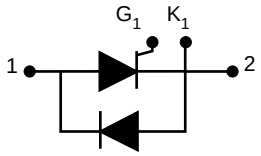


Fig.2 Single circuit

VOLTAGE RATINGS

Type Number	Repetitive Peak Off-state Voltage V_{DRM} V	Conditions
MAS110S 14	1400	T_{vj} = 125°C, I_{DRM} = 50mA, $V_{DSM} = V_{DRM}$ + 100V
MAS110S 12	1200	
MAS110S 10	1000	
MAS110S 08	800	
MAS110S 06	600	

For full description of part number see 'Ordering Information'.

THYRISTOR CURRENT RATINGS

Symbol	Parameter	Conditions	Max.	Units
$I_{T(AV)}$	Mean forward current	Half wave resistive load, T_{case} = 75°C	110	A
$I_{T(RMS)}$	RMS value	T_{case} = 75°C	175	A

THYRISTOR SURGE RATINGS

Symbol	Parameter	Conditions	Max.	Units
I_{TSM}	Surge (non-repetitive) on-state current	10ms half sine; T_{case} = 125°C	2.0	kA
I^2t	I^2t for fusing	V_R = 0% V_{DRM}	20.0 x 10^3	A^2s

THYRISTOR DYNAMIC CHARACTERISTICS

Symbol	Parameter	Conditions		Min.	Max.	Units
V_{TM}	Maximum on-state voltage	At 600A peak, T_{case} = 25°C		-	2.9	V
I_{DRM}	Peak off-state current	At V_{DRM}, T_{case} = 125°C		-	70	mA
dV/dt	Maximum linear rate of rise of off-state voltage	To 60% V_{DRM} T_j = 125°C, Gate open circuit		-	1000	V/µs
dI/dt	Rate of rise of on-state current	From 67% V_{DRM} to 600A, Gate source 20V, 20Ω t_r = < 0.5µs, T_j = 125˚C	Repetitive 50Hz	-	500	A/µs
$V_{T(TO)}$	Threshold voltage	At T_{vj} = 125°C		-	1.6	V
r_T	On-state slope resistance	At T_{vj} = 125°C		-	1.4	mΩ
t_q	Turn-off time	I_T = 100A, T_j = 125˚C, dI_R/dt = 30A/µs, V_{GK} = 0V dV/dt = 20V/µs to 60% V_{DRM}, V_R = 1V.	t_q code: W	-	10	µs
			t_q code: S	-	12	µs
			t_q code: X	-	15	µs

THYRISTOR GATE TRIGGER CHARACTERISTICS AND RATINGS

Symbol	Parameter	Conditions	Typ.	Max.	Units
V_{GT}	Gate trigger voltage	V_{DRM} = 12V, T_{case} = 25°C, R_L = 30Ω	-	4.0	V
I_{GT}	Gate trigger current	V_{DRM} = 12V, T_{case} = 25°C	-	250	mA
V_{RGM}	Peak reverse gate voltage		-	7.0	V
I_{FGM}	Peak forward gate current	Anode positive with respect to cathode	-	10	A
P_{GM}	Peak gate power	-	-	50	W
$P_{G(AV)}$	Mean gate power	Average timing = 10ms	-	15	W

DIODE CURRENT RATINGS

Symbol	Parameter	Conditions	Max.	Units
$I_{T(AV)}$	Mean forward current	Half wave resistive load, T_{case} = 75°C	112	A
$I_{T(RMS)}$	RMS value	T_{case} = 75°C	175	A

DIODE SURGE RATINGS - PER ARM

Symbol	Parameter	Conditions	Max.	Units
I_{FSM}	Surge (non-repetitive) forward current	10ms half sine; T_{case} = 130°C	3.5	kA
I^2t	I^2t for fusing	V_R = 0% V_{RRM}	61.25×10^3	A^2s

DIODE DYNAMIC CHARACTERISTICS

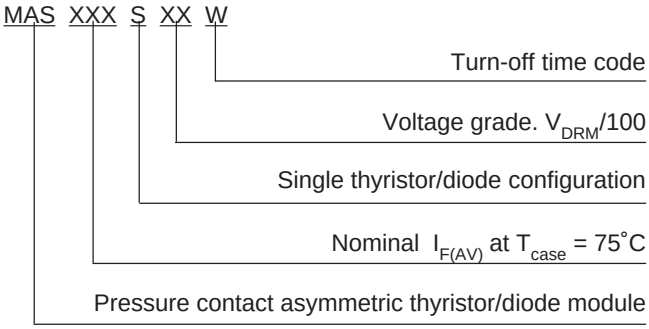
Symbol	Parameter	Conditions	Max.	Units
V_{FM}	Forward voltage	At 600A, T_{case} = 25°C.	2.65	V
I_{RRM}	Peak reverse current	At V_{RRM}, T_{case} = 125°C.	70	mA
t_{rr}	Reverse recovery time	T_{case} = 125°C, dI_R/dt = -50V/µs, I_{FM} = 200A	1.3	µs
V_{TO}	Threshold voltage	At T_{vj} = 125°C.	1.6	V
r_T	Forward slope resistance	At T_{vj} = 125°C.	1.5	mΩ

THERMAL AND MECHANICAL DATA

Symbol	Parameter	Conditions	Min.	Max.	Units
$R_{th(j-c)}$	Thermal resistance - junction to case (Thyristor or diode)	dc	-	0.21	°C/W
$R_{th(c-h)}$	Thermal resistance - case to heatsink (Thyristor or diode)	Mounting force 6Nm with mounting compound.	-	0.07	°C/W
T_{vj}	Virtual junction temperature	-	-	125	°C
T_{op}	Operating temperature range	-	-40	125	°C
T_{stg}	Storage temperature range		-40	125	°C
V_{isol}	Isolation voltage	Commoned terminals to base plate. AC RMS, 1 min, 50Hz.	-	2.5	kV
-	Mounting torque		-	6.0	Nm

ORDERING INFORMATION

The module type number is made up as follows:



Examples:

MAS 110 S 12 W
MAS 110 S 08 X

MODULE MOUNTING RECOMMENDATIONS

■ Adequate heatsinking is required to maintain the base temperature at 75°C if full rated current is to be achieved. Power dissipation may be calculated by use of $V_{T(TO)}$ and r_T information and loss curves in accordance with standard formulae. We can provide assistance with calculations or choice of heatsink if required.

■ The heatsink surface must be smooth and flat; a surface finish of N6 (32µin) and a flatness within 0.05mm (0.002") are recommended.

■ Immediately prior to mounting, the heatsink surface should be lightly scrubbed with fine emery, Scotch Brite™ or a mild chemical etchant and then cleaned with a solvent to remove oxide build up and foreign material. Care should be taken to ensure no foreign particles remain.

■ An even coating of thermal compound (eg. Unial) should be applied to both the heatsink and module mounting surfaces. This should ideally be 0.05mm (0.002") per surface to ensure optimum thermal performance.

■ After application of thermal compound, place the module squarely over the mounting holes, (or 'T' slots) in the heatsink. Using a torque wrench, slowly tighten the recommended fixing bolts at each end, rotating each in turn no more than 1/4 of a revolution at a time. Continue until the required torque of 6Nm (55lb.ins) is reached at both ends.

■ It is not acceptable to fully tighten one fixing bolt before starting to tighten the others. Such action may DAMAGE the module.

Curves

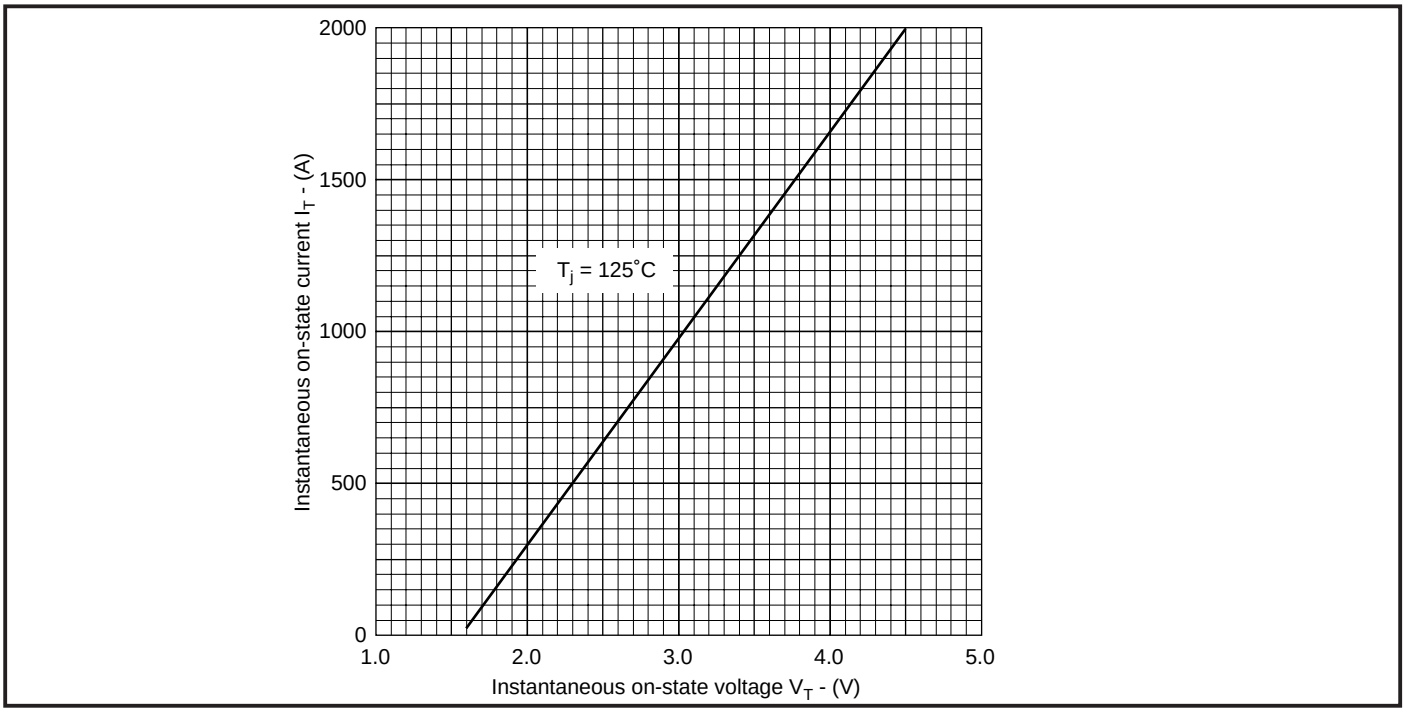


Fig.3 Maximum (limit) on-state characteristics (thyristor only)

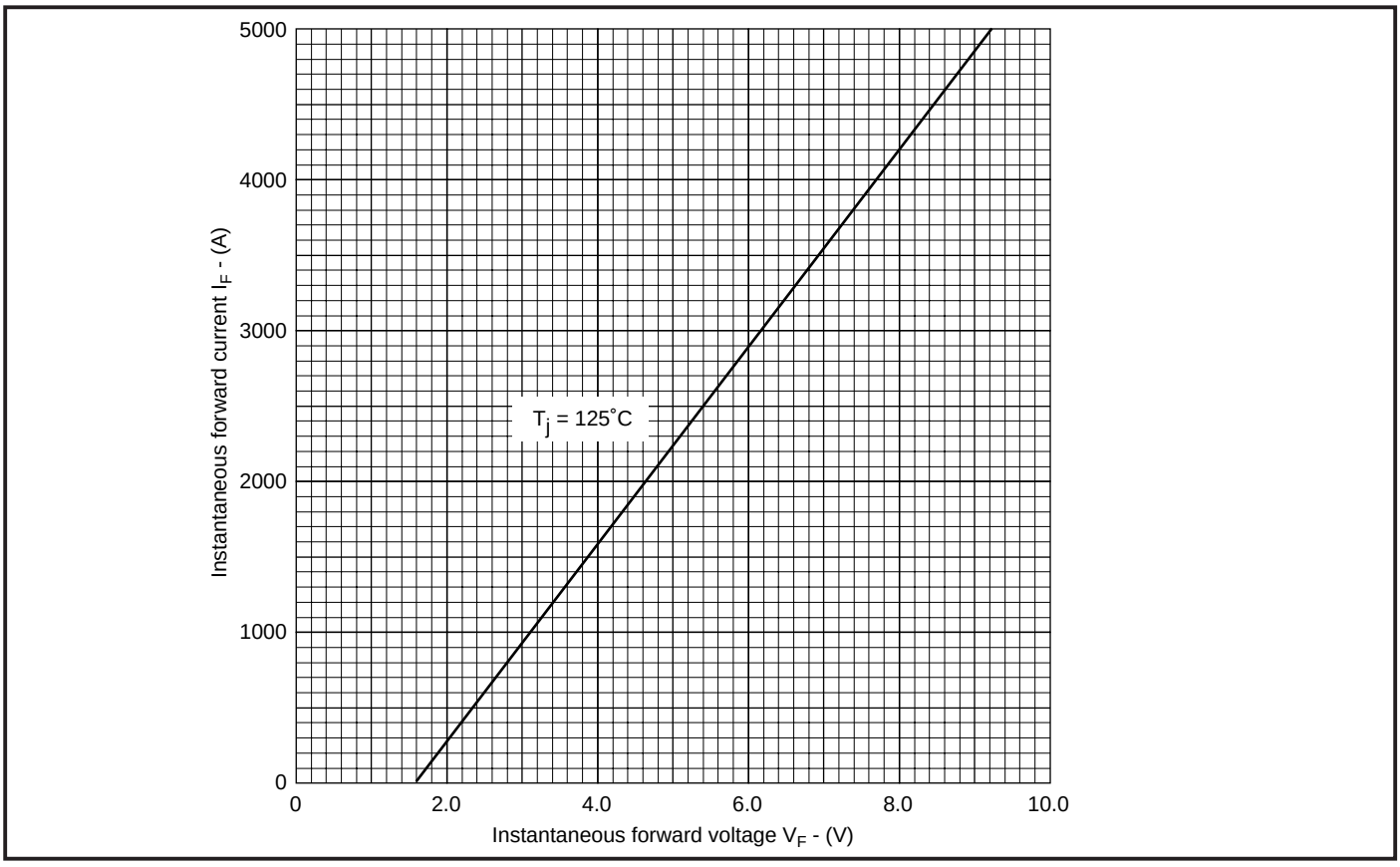


Fig.4 Maximum (limit) forward characteristics (diode only)

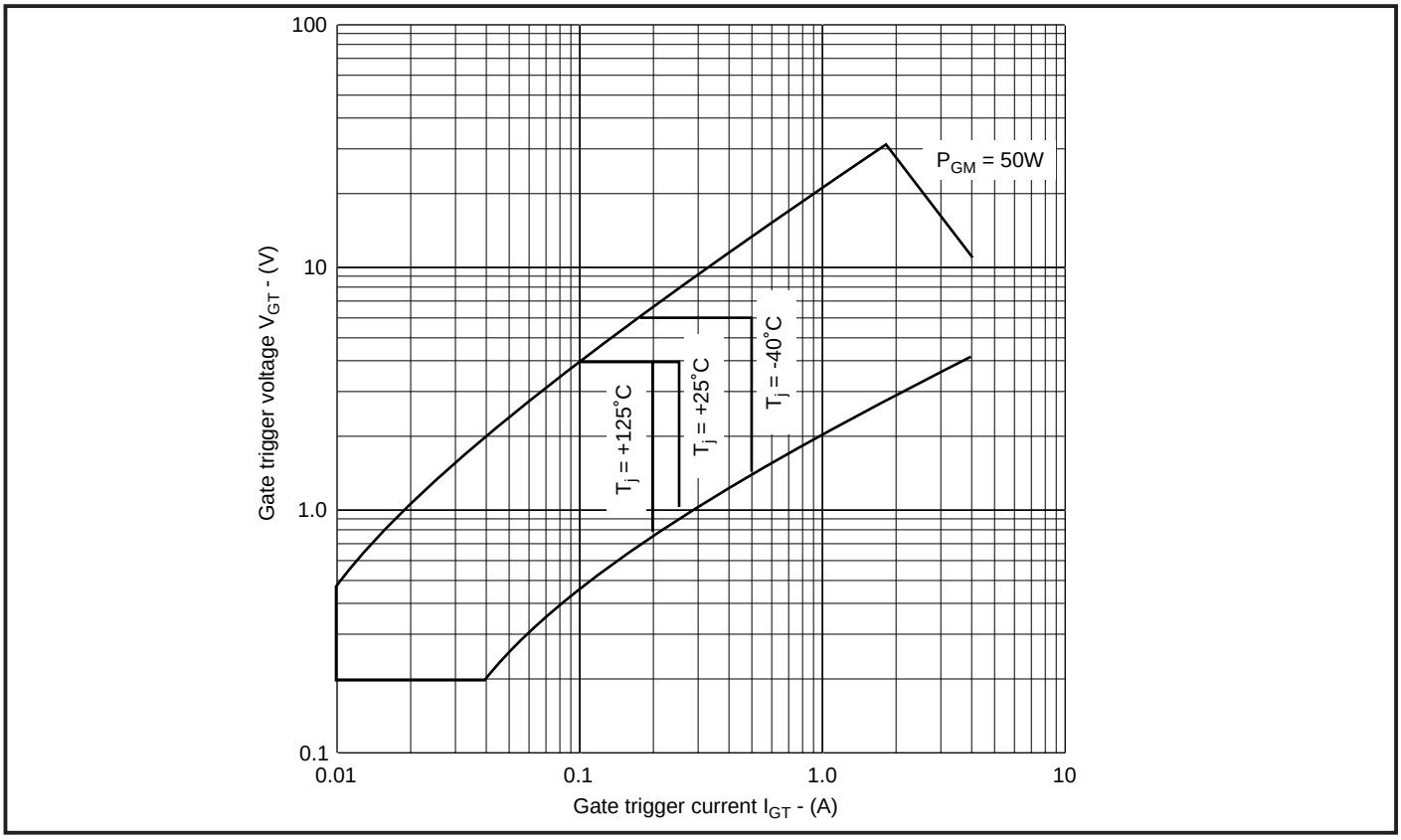


Fig.5 Gate characteristics

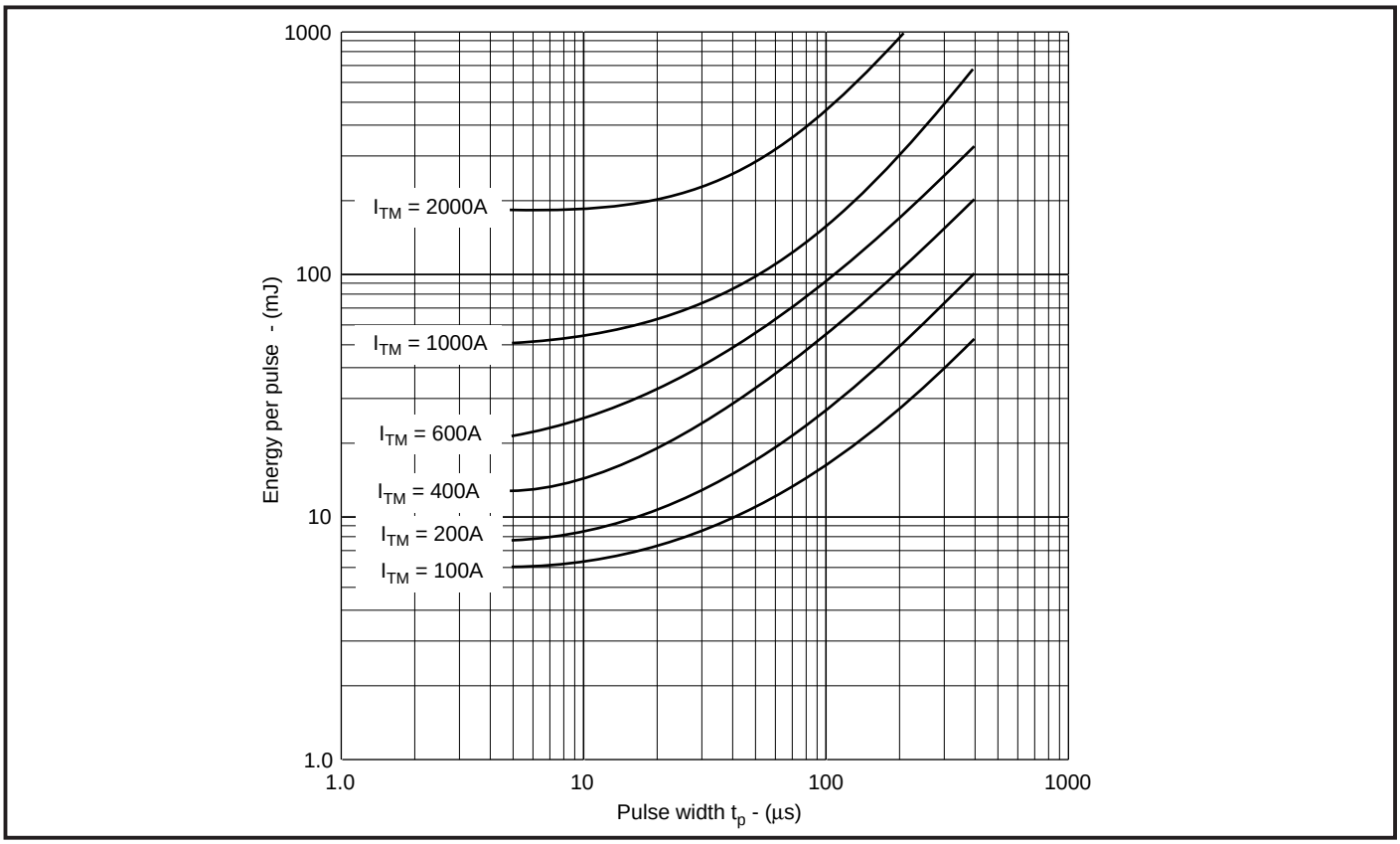


Fig.6 Sinusoidal energy per pulse (thyristor only)

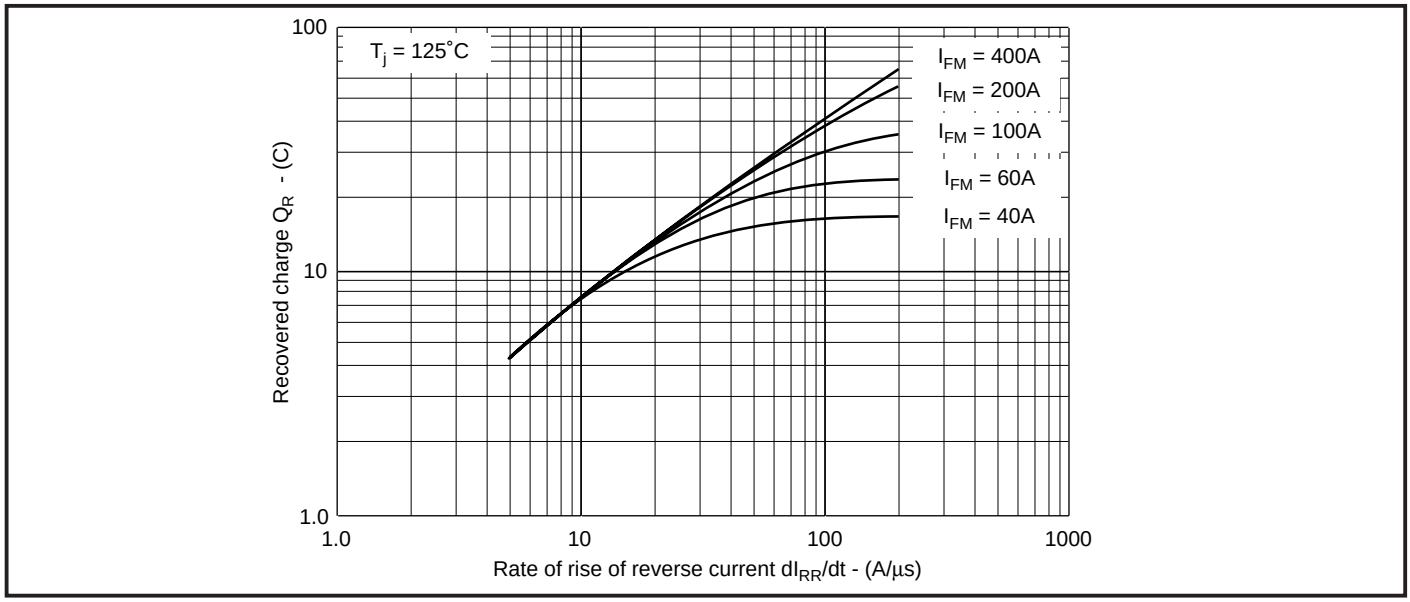


Fig.7 Recovered charge (diode only)

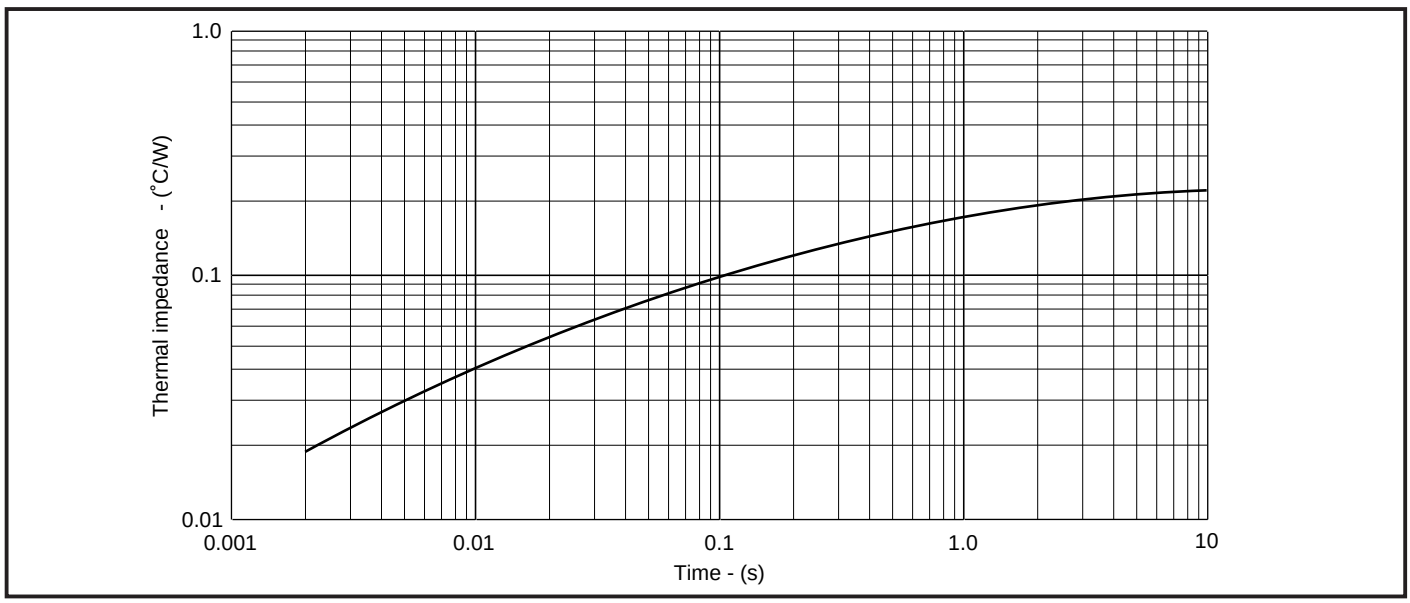
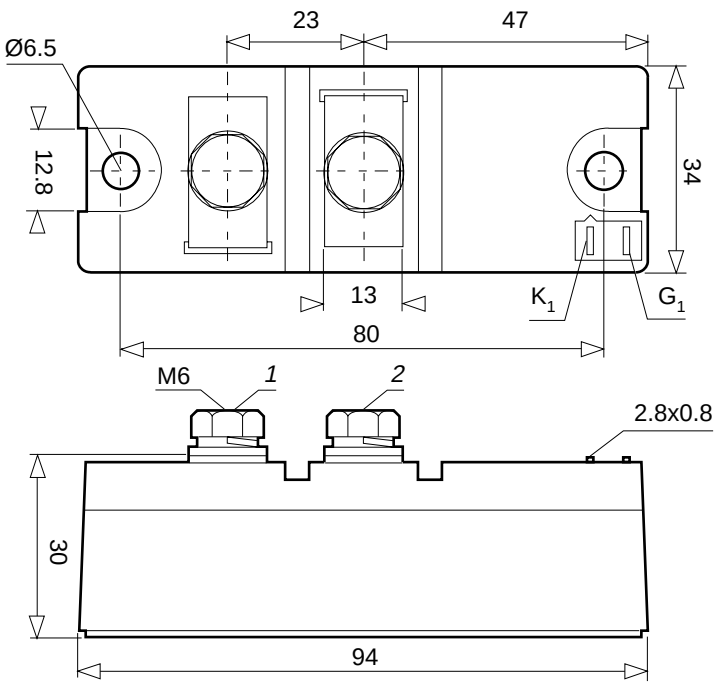


Fig.8 Maximum (limit) transient thermal impedance (thyristor only)

PACKAGE DETAILS

For further package information, please contact your local Customer Service Centre. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



Recommended fixings for mounting:	M6 socket head cap screws.
Recommended mounting torque:	6Nm (55lb.ins)
Recommended torque for electrical connections:	5Nm (44lb.ins)
Maximum torques for electrical connections:	8Nm (70lb.ins)
Nominal weight:	350g

Module outline type code: MP02

POWER ASSEMBLY CAPABILITY

The Power Assembly group was set up to provide a support service for those customers requiring more than the basic semiconductor, and has developed a flexible range of heatsink / clamping systems in line with advances in device types and the voltage and current capability of our semiconductors.

We offer an extensive range of air and liquid cooled assemblies covering the full range of circuit designs in general use today. The Assembly group continues to offer high quality engineering support dedicated to designing new units to satisfy the growing needs of our customers.

Using the up to date CAD methods our team of design and applications engineers aim to provide the Power Assembly Complete solution (PACs).

HEATSINKS

Power Assembly has it's own proprietary range of extruded aluminium heatsinks. They have been designed to optimise the performance or our semiconductors. Data with respect to air natural, forced air and liquid cooling (with flow rates) is available on request.

For further information on device clamps, heatsinks and assemblies, please contact your nearest Sales Representative or the factory.

http://www.dynexsemi.com

e-mail: power_solutions@dynexsemi.com

HEADQUARTERS OPERATIONS
DYNEX SEMICONDUCTOR LTD
Doddington Road, Lincoln.
Lincolnshire. LN6 3LF. United Kingdom.
Tel: 00-44-(0)1522-500500
Fax: 00-44-(0)1522-500550

DYNEX POWER INC.
Unit 7 - 58 Antares Drive,
Nepean, Ontario, Canada K2E 7W6.
Tel: 613.723.7035
Fax: 613.723.1518
Toll Free: 1.888.33.DYNEX (39639)

CUSTOMER SERVICE CENTRES
France, Benelux, Italy and Spain Tel: +33 (0)1 69 18 90 00. Fax: +33 (0)1 64 46 54 50
North America Tel: 011-800-5554-5554. Fax: 011-800-5444-5444
UK, Germany, Scandinavia & Rest Of World Tel: +44 (0)1522 500500. Fax: +44 (0)1522 500020

SALES OFFICES
France, Benelux, Italy and Spain Tel: +33 (0)1 69 18 90 00. Fax: +33 (0)1 64 46 54 50
Germany Tel: 07351 827723
North America Tel: (613) 723-7035. Fax: (613) 723-1518. Toll Free: 1.888.33.DYNEX (39639) /
Tel: (831) 440-1988. Fax: (831) 440-1989 / Tel: (949) 733-3005. Fax: (949) 733-2986.
UK, Germany, Scandinavia & Rest Of World Tel: +44 (0)1522 500500. Fax: +44 (0)1522 500020
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